

## **FDA28N50** N-Channel UniFET<sup>TM</sup> MOSFET 500 V, 28 A, 155 mΩ

### Features

- $R_{DS(on)}$  = 122 m $\Omega$  (Typ.) @ V<sub>GS</sub> = 10 V, I<sub>D</sub> = 14 A
- Low Gate Charge (Typ. 80 nC)
- Low C<sub>rss</sub> (Typ. 42 pF)
- 100% Avalanche Tested
- RoHS Compliant

### Applications

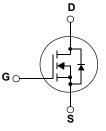
- PDP TV
- Uninterruptible Power Supply
- AC-DC Power Supply

# Description

UniFET<sup>TM</sup> MOSFET is Fairchild Semiconductor<sup>®</sup>'s high voltage MOSFET family based on planar stripe and DMOS technology. This MOSFET is tailored to reduce on-state resistance, and to provide better switching performance and higher avalanche energy strength. This device family is suitable for switching power converter applications such as power factor correction (PFC), flat panel display (FPD) TV power, ATX and electronic lamp ballasts.

March 2013





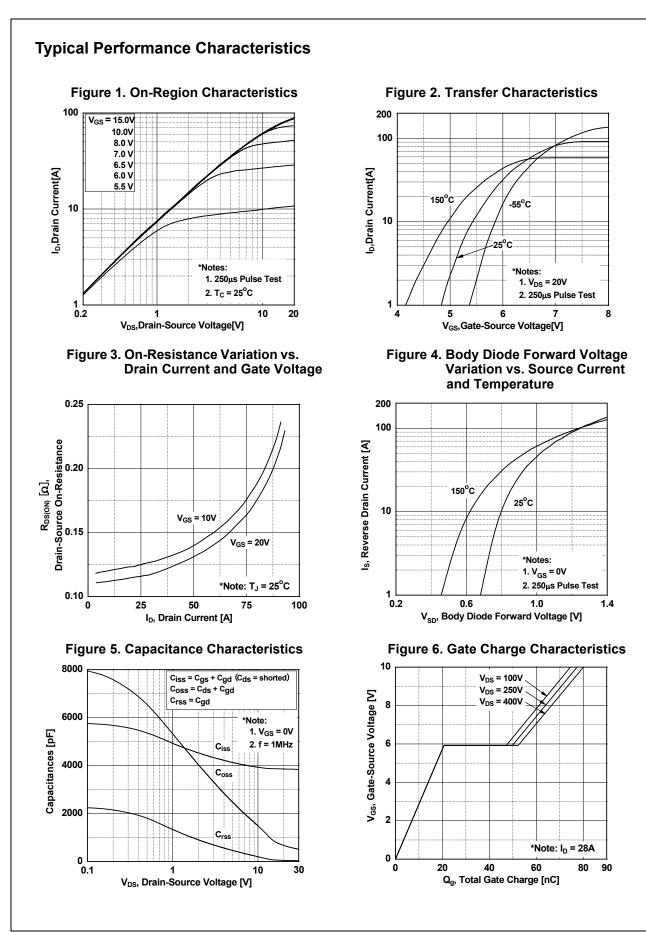
### MOSFET Maximum Ratings T<sub>C</sub> = 25°C unless otherwise noted

Symbol	Parameter			FDA28N50	Unit	
V <sub>DSS</sub>	Drain to Source Voltage			500	V	
V <sub>GSS</sub>	Gate to Source Voltage			±30	V	
I <sub>D</sub>	Drain Current	- Continuous (T <sub>C</sub> = 25 <sup>o</sup> C)		28	•	
		- Continuous (T <sub>C</sub> = 100 <sup>o</sup> C)		17	— A	
I <sub>DM</sub>	Drain Current	- Pulsed	(Note 1)	112	А	
E <sub>AS</sub>	Single Pulsed Avalanche E	Energy	(Note 2)	2391	mJ	
I <sub>AR</sub>	Avalanche Current		(Note 1)	28	А	
E <sub>AR</sub>	Repetitive Avalanche Ener	ду	(Note 1)	31	mJ	
dv/dt	Peak Diode Recovery dv/dt		(Note 3)	5	V/ns	
P <sub>D</sub>	Deven Dia sin atian	$(T_{\rm C} = 25^{\rm o}{\rm C})$		310	W	
	Power Dissipation	- Derate above 25°C		2.5	W/ºC	
T <sub>J</sub> , T <sub>STG</sub>	Operating and Storage Temperature Range			-55 to +150	°C	
TL	Maximum Lead Temperature for Soldering Purpose, 1/8" from Case for 5 Seconds			300	°C	

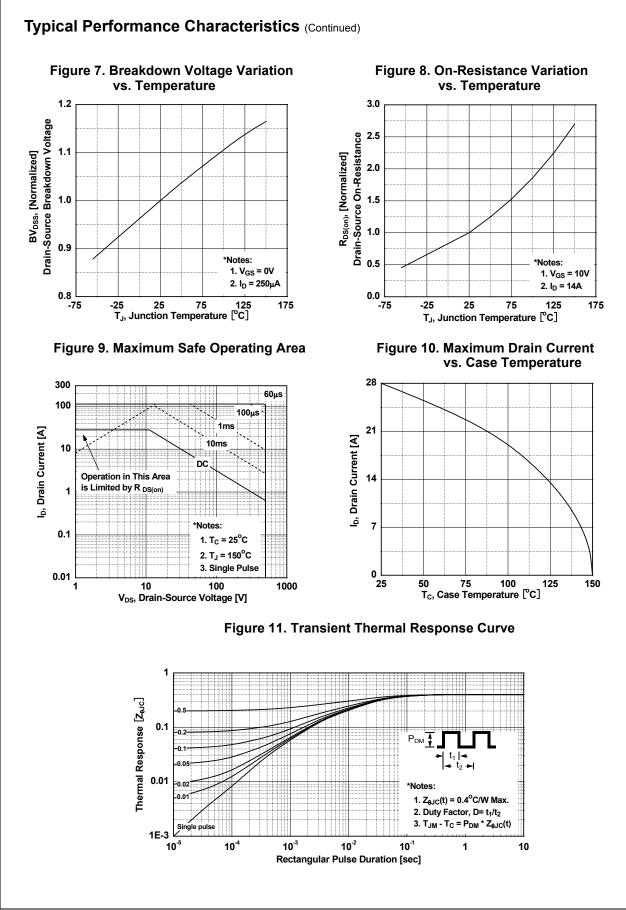
### Thermal Characteristics

Symbol	Parameter	FDA28N50	Unit
$R_{ ext{ heta}JC}$	Thermal Resistance, Junction to Case, Max.	0.4	
$R_{\theta CS}$	Thermal Resistance, Case to Sink Typ.	0.24	°C/W
$R_{ hetaJA}$	Thermal Resistance, Junction to Ambient, Max.	40	

	Device Marking Device Pa		Package	e Reel Size	Тар	e Width		Quantity	
		TO-3PN	-		-		50		
							i		
			25°C unless o				<b></b>		· · · · ·
Symbol		Parameter		Test Conditions		Min.	Тур.	Max.	Unit
Off Charac	cteristics:	5							
BV <sub>DSS</sub>	Drain to	to Source Breakdown Voltage		$I_D = 250 \mu A, V_{GS} = 0V, T_J = 25^{\circ}C$		500	-	-	V
$\Delta BV_{DSS}$ $\Delta T_J$	Breakdo	Breakdown Voltage Temperature Coefficient		$I_D = 250\mu$ A, Referenced to $25^{\circ}$ C		-	0.59	-	V/ºC
				V <sub>DS</sub> = 500V, V <sub>GS</sub> = 0V		-	-	1	<u> </u>
I <sub>DSS</sub>	Zero Gate Voltage Drain Current		ent	$V_{\rm DS} = 400V, T_{\rm C} = 125^{\rm o}{\rm C}$		-	-	10	μA
I <sub>GSS</sub>	Gate to	Body Leakage Currer	nt	$V_{GS} = \pm 30V, V_{DS} = 0V$		-	-	±100	nA
		· · ·			1			1	
On Charac	teristics	\$						<u>.</u>	
V <sub>GS(th)</sub>	Gate Th	reshold Voltage		$V_{GS} = V_{DS}, I_D = 250 \mu A$		3.0	-	5.0	V
R <sub>DS(on)</sub>		rain to Source On Res	sistance	V <sub>GS</sub> = 10V, I <sub>D</sub> = 14A		-	0.122	0.155	Ω
9 <sub>FS</sub>	Forward	I Transconductance		V <sub>DS</sub> = 20V, I <sub>D</sub> = 14A		-	34	-	S
Dynamic C	haracte	ristics							
C <sub>iss</sub>	Input Ca	apacitance				-	3866	5140	pF
C <sub>oss</sub>	Output C	Capacitance		V <sub>DS</sub> = 25V, V <sub>GS</sub> = 0V f = 1MHz	Ē	-	576	766	pF
C <sub>rss</sub>	-	Transfer Capacitance	e		ŀ	-	42	63	pF
Q <sub>g(tot)</sub>		te Charge at 10V				-	80	105	nC
Q <sub>gs</sub>	Gate to :	Source Gate Charge		$V_{DS} = 400V, I_D = 28A$ $V_{GS} = 10V$ (but t)		-	21	-	nC
Q <sub>gd</sub>	Gate to	Drain "Miller" Charge				-	32	-	nC
Switching		0			(Note 4)			<u> </u>	
-							56	400	
t <sub>d(on)</sub>		Delay Time		V <sub>DD</sub> = 250V, I <sub>D</sub> = 28A		-	56	122	ns
t <sub>r</sub>		Rise Time		$R_{G} = 25\Omega$	-	-	126	262	ns
t <sub>d(off)</sub>		Delay Time				-	210	430	ns
t <sub>f</sub>	Turn-On	Fall Time			(Note 4)	-	110	230	ns
Drain-Sou	rce Diod	le Characteristic	s						
I <sub>S</sub>		m Continuous Drain to				-	-	28	Α
I <sub>SM</sub>	Maximum Pulsed Drain to Source Diode F		Irce Diode Forv			-		112	Α
V <sub>SD</sub>	Drain to	Source Diode Forwar	d Voltage	$V_{GS}$ = 0V, $I_{SD}$ = 28A		-	-	1.4	V
t <sub>rr</sub>	Reverse	Recovery Time		V <sub>GS</sub> = 0V, I <sub>SD</sub> = 28A		-	530	-	ns
Q <sub>rr</sub>	Dovoroo	Recovery Charge		dI <sub>F</sub> /dt = 100A/μs		-	8	-	μC

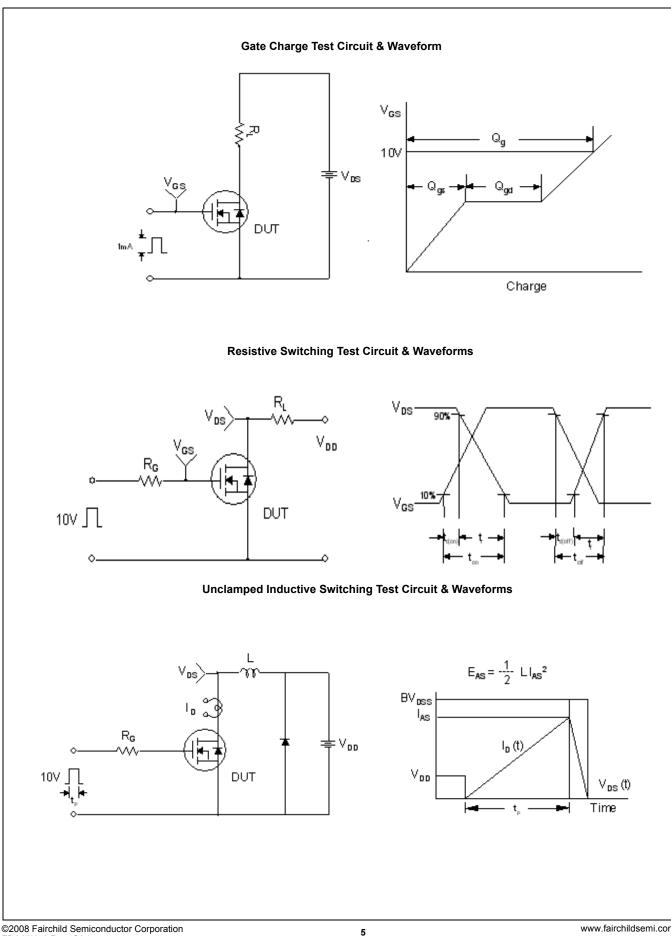


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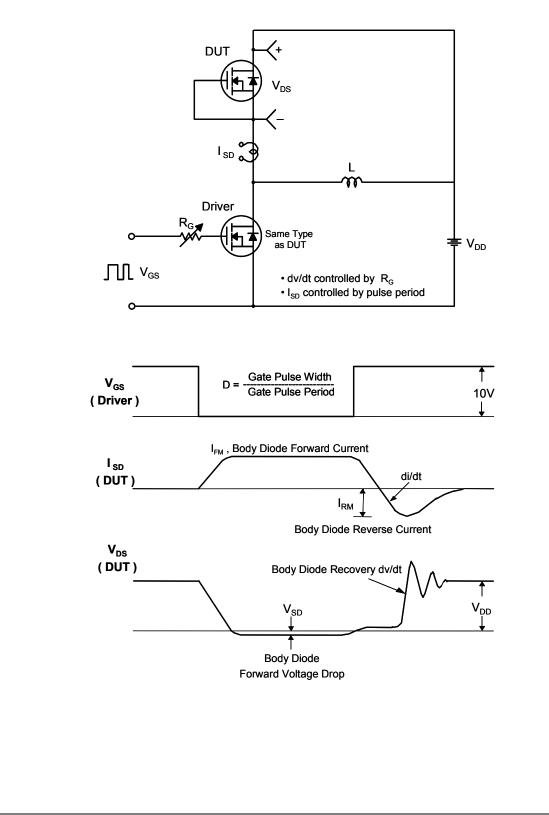
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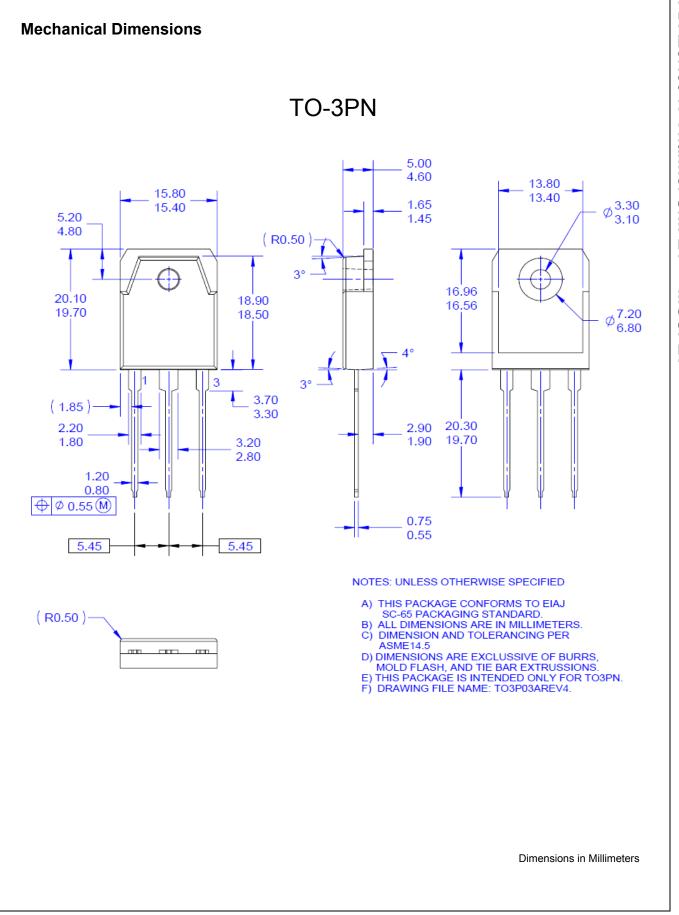
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### Peak Diode Recovery dv/dt Test Circuit & Waveforms







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